

# Santhosh Kumar M C

## List of Publications by Year in descending order

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86  
papers

2,226  
citations

270111

25  
h-index

263392

45  
g-index

86  
all docs

86  
docs citations

86  
times ranked

2475  
citing authors

#	ARTICLE	IF	CITATIONS
1	Study on ferroelectric polarization induced resistive switching characteristics of neodymium-doped bismuth ferrite thin films for random access memory applications. <i>Current Applied Physics</i> , 2022, 39, 221-229.	1.1	9
2	Optoelectronic properties of transparent conducting CdO:ZnO composite thin films by RF-magnetron sputtering. <i>Journal of Materials Science: Materials in Electronics</i> , 2022, 33, 15638-15651.	1.1	1
3	Enhanced physical properties of ZEO thin films for device applications. <i>Materials Today: Proceedings</i> , 2021, 39, 1620-1624.	0.9	0
4	Influence of deposition time on the visible-light-driven photocatalytic activity of Cu <sub>2</sub> O thin films by reactive sputtering at room temperature. <i>Materials Letters</i> , 2021, 284, 128980.	1.3	12
5	X-ray computed tomography and thermal neutron radiography for detection of low dense compounds inside pyro elements used in space applications. <i>European Physical Journal Plus</i> , 2021, 136, 1.	1.2	1
6	Effect of hydrophilic coating on mesh wicks used in heat pipes. <i>Surface Engineering</i> , 2020, 36, 680-686.	1.1	11
7	Ferroelectric polarization induced memristive behavior in bismuth ferrite (BiFeO <sub>3</sub> ) based memory devices. <i>Superlattices and Microstructures</i> , 2020, 148, 106726.	1.4	14
8	Fabrication and characterization of resistive random access memory (ReRAM) devices using molybdenum trioxide (MoO <sub>3</sub> ) as switching layer. <i>Superlattices and Microstructures</i> , 2020, 147, 106682.	1.4	21
9	Realization of In:ZnO/PEDOT:PSS based multifunctional device for ultraviolet (UV) light detection and resistive switching memory applications. <i>Journal of Applied Physics</i> , 2020, 128, 044503.	1.1	11
10	Deposition and characterization of earth abundant CuZnS ternary thin films by vacuum spray pyrolysis and fabrication of p-CZS/n-AZO heterojunction solar cells. <i>International Journal of Energy Research</i> , 2020, 44, 7778-7788.	2.2	10
11	Analysis on different detection mechanisms involved in ZnO-based photodetector and photodiodes. <i>Journal of Materials Science: Materials in Electronics</i> , 2020, 31, 7100-7113.	1.1	47
12	Room temperature deposition of high figure of merit p-type transparent conducting Cu <sub>1-x</sub> Zn <sub>x</sub> S thin films and their application in organic solar cells as an efficient hole transport layer. <i>Journal of Alloys and Compounds</i> , 2020, 829, 154507.	2.8	9
13	On the conversion of amorphous In <sub>2</sub> S <sub>3</sub> thin films to polycrystalline In <sub>2</sub> S <sub>3</sub> and to In <sub>2</sub> O <sub>3</sub> through thermal oxidation process. <i>Materials Science in Semiconductor Processing</i> , 2020, 111, 104983.	1.9	14
14	Effect of substrate temperature on properties of co-evaporated copper antimony sulfide thin films. <i>Thin Solid Films</i> , 2020, 697, 137838.	0.8	8
15	Detection and Characterisation of Low Dense Charges Inside Metallic Devices Used in Space Applications by Neutron Radiography. <i>Journal of Nondestructive Evaluation</i> , 2020, 39, 1.	1.1	2
16	Synergetic effects of aluminium and indium dopants in the physical properties of ZnO thin films via spray pyrolysis. <i>Superlattices and Microstructures</i> , 2020, 142, 106511.	1.4	17
17	A Study on the Emergence of P-Type Behaviour in Sr-Cu-O Mixed Phase Systems. <i>Journal of Physics: Conference Series</i> , 2019, 1172, 012008.	0.3	0
18	Indium sulfide based metal-semiconductor-metal ultraviolet-visible photodetector. <i>Sensors and Actuators A: Physical</i> , 2019, 299, 111643.	2.0	26

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19	Biocidal properties of sputtered CdO:ZnO multi-component thin films for potential use in pathogenic bacteria control. <i>Materials Research Express</i> , 2019, 6, 104009.	0.8	6
20	Fabrication of visible light photodetector using co-evaporated Indium Sulfide thin films. <i>Journal of Materials Science: Materials in Electronics</i> , 2019, 30, 17986-17998.	1.1	13
21	Effect of oxygen partial pressure on the tuning of copper oxide thin films by reactive sputtering for solar light driven photocatalysis. <i>Solar Energy</i> , 2019, 187, 368-378.	2.9	36
22	Enhanced luminescence property of 1 D nanorods realised by aqueous chemical growth on indium doped zinc oxide thin films. <i>Thin Solid Films</i> , 2019, 686, 137279.	0.8	8
23	Surfactant-mediated solvothermal synthesis of CuSbS <sub>2</sub> nanoparticles as p-type absorber material. <i>Indian Journal of Physics</i> , 2019, 93, 185-195.	0.9	8
24	Properties of Au incorporated In <sub>2</sub> O <sub>3</sub> films. <i>Materials Science in Semiconductor Processing</i> , 2019, 93, 134-147.	1.9	14
25	Effect of Zn/Sn molar ratio on the microstructural and optical properties of Cu <sub>2</sub> Zn <sub>1-x</sub> Sn <sub>x</sub> S <sub>4</sub> thin films prepared by spray pyrolysis technique. <i>Physica B: Condensed Matter</i> , 2018, 533, 22-27.	1.3	16
26	Post-deposition thermal treatment of sprayed ZnO:Al thin films for enhancing the conductivity. <i>Physica B: Condensed Matter</i> , 2018, 533, 83-89.	1.3	19
27	Effect of substrate temperature and oxygen partial pressure on RF sputtered NiO thin films. <i>Materials Research Express</i> , 2018, 5, 046401.	0.8	20
28	An investigation on the In doping of ZnO thin films by spray pyrolysis. <i>AIP Conference Proceedings</i> , 2018, , .	0.3	1
29	Modeling of Fume Formation from Shielded Metal Arc Welding Process. <i>Metallurgical and Materials Transactions B: Process Metallurgy and Materials Processing Science</i> , 2017, 48, 1268-1278.	1.0	1
30	Room temperature deposition of highly crystalline Cu-Zn-S thin films for solar cell applications using SILAR method. <i>Journal of Alloys and Compounds</i> , 2017, 712, 649-656.	2.8	27
31	High-speed photoresponse properties of ultraviolet (UV) photodiodes using vertically aligned Al:ZnO nanowires. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2017, 214, 1600658.	0.8	10
32	Deposition rate dependant formation and properties of Sn <sub>2</sub> S <sub>3</sub> and SnS thin films by co-evaporation. <i>Materials Research Express</i> , 2017, 4, 046404.	0.8	9
33	Effect of annealing on the optical properties and photoconductivity of SnS thin film. <i>AIP Conference Proceedings</i> , 2017, , .	0.3	5
34	Solution Processed p-Type Cu <sub>2</sub> ZnSnS <sub>4</sub> Thin Films for Absorber Layer. <i>Journal of Inorganic and Organometallic Polymers and Materials</i> , 2017, 27, 1556-1562.	1.9	5
35	Control of exposure to hexavalent chromium concentration in shielded metal arc welding fumes by nano-coating of electrodes. <i>International Journal of Occupational and Environmental Health</i> , 2017, 23, 128-142.	1.2	8
36	Role of Oxygen Interstitial Defects in Fabrication of UV Photodiodes Using Vertically Aligned (Al,Ga):ZnO Nanowires. <i>Nanoscience and Nanotechnology Letters</i> , 2017, 9, 489-495.	0.4	4

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37	Effect of substrate temperature on the physical properties of co-evaporated Sn <sub>2</sub> S <sub>3</sub> thin films. <i>Ceramics International</i> , 2016, 42, 12262-12269.	2.3	50
38	Room-temperature wide-range luminescence and structural, optical, and electrical properties of SILAR deposited Cu-Zn-S nano-structured thin films. , 2016, , .		4
39	Co-evaporated SnS thin films for visible light photodetector applications. <i>RSC Advances</i> , 2016, 6, 95680-95692.	1.7	134
40	Effect of Nb doping on the structural, morphological, optical and electrical properties of RF magnetron sputtered In <sub>2</sub> O <sub>3</sub> nanostructured films. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2016, 14, 1600095.	0.8	7
41	Role of p-NiO electron blocking layers in fabrication of (P-N):ZnO/Al:ZnO UV photodiodes. <i>Current Applied Physics</i> , 2016, 16, 1052-1061.	1.1	27
42	Highly transparent conducting CdO thin films by radiofrequency magnetron sputtering for optoelectronic applications. <i>Journal of Nanophotonics</i> , 2016, 10, 033007.	0.4	25
43	Effect of surfactant addition on hydrophilicity of ZnO-Al <sub>2</sub> O <sub>3</sub> composite and enhancement of flow boiling heat transfer. <i>Experimental Thermal and Fluid Science</i> , 2016, 70, 325-334.	1.5	19
44	Application of Taguchi method in the optimization of process parameters for a sol-gel-derived nano-alumina film. <i>Proceedings of the Institution of Mechanical Engineers, Part L: Journal of Materials: Design and Applications</i> , 2016, 230, 574-585.	0.7	3
45	Heat Treatment Impact on the Properties of Na and N Dual Doped ZnO Thin Flms by Spray Pyrolysis. , 2015, 10, 714-722.		2
46	Effect of Post-Annealing on the Properties of Eu Doped ZnO Nano Thin Films. , 2015, 10, 723-729.		21
47	Welding fumes reduction by coating of nano-TiO <sub>2</sub> on electrodes. <i>Journal of Materials Processing Technology</i> , 2015, 219, 237-247.	3.1	22
48	Investigation on P-N dual acceptor doped p-type ZnO thin films and subsequent growth of pencil-like nanowires. <i>Semiconductor Science and Technology</i> , 2015, 30, 035009.	1.0	18
49	Welding fume reduction by nano-alumina coating on electrodes towards green welding process. <i>Journal of Cleaner Production</i> , 2015, 108, 131-144.	4.6	31
50	Deposition and characterization of Cu <sub>2</sub> SnS <sub>3</sub> thin films by co-evaporation for photovoltaic application. <i>Solar Energy Materials and Solar Cells</i> , 2015, 143, 128-134.	3.0	68
51	Growth and characterization of near white light emitting Al-Ga:ZnO nanowires. <i>Materials Research Express</i> , 2015, 2, 075004.	0.8	7
52	Realization of highly transparent conducting CdO thin films by R.F. Magnetron sputtering for optoelectronic applications. , 2015, , .		0
53	Fabrication and characterization of p-ZnO:(P,N)/n-ZnO:Al homojunction ultra-violet (UV) light emitting diodes (Presentation Recording). , 2015, , .		0
54	Flow boiling heat transfer enhancement on copper surface using Fe doped Al <sub>2</sub> O <sub>3</sub> -TiO <sub>2</sub> composite coatings. <i>Applied Surface Science</i> , 2015, 334, 102-109.	3.1	42

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55	Fabrication and characterization of n-ZnO:Eu/p-ZnO:(Ag, N) homojunction by spray pyrolysis. Materials Research Bulletin, 2014, 49, 44-49.	2.7	7
56	Epitaxial growth of vertically aligned highly conducting ZnO nanowires by modified aqueous chemical growth process. Ceramics International, 2014, 40, 11283-11290.	2.3	21
57	Optical properties of samarium doped ZnO thin films. , 2014, , .		2
58	Enhanced visible emission from vertically aligned ZnO nanostructures by aqueous chemical growth process. Journal of Luminescence, 2014, 155, 149-155.	1.5	34
59	Dual acceptor doping and aging effect of p-ZnO:(Na, N) nanorod thin films by spray pyrolysis. , 2014, , .		3
60	Deposition of the low resistive Ag <sup>+</sup> /N dual acceptor doped p-type ZnO thin films. Ceramics International, 2013, 39, 1799-1806.	2.3	24
61	Deposition of Na <sup>+</sup> /N dual acceptor doped p-type ZnO thin films and fabrication of p-ZnO:(Na,) Tj ETQq1 1 0.784314 rgBT /Overlock 10 Technology, 2013, 178, 1032-1039.	1.7	40
62	Growth and characterization of molybdenum doped ZnO thin films by spray pyrolysis. Journal of Physics and Chemistry of Solids, 2013, 74, 418-425.	1.9	49
63	Microstructural, electrical and optical properties of ZnO:Mo thin films with various thickness by spray pyrolysis. Journal of Analytical and Applied Pyrolysis, 2013, 102, 68-75.	2.6	59
64	Aging and annealing effects on properties of Ag-N dual-acceptor doped ZnO thin films. , 2013, , .		3
65	Effects of thickness and atmospheric annealing on structural, electrical and optical properties of GZO thin films by spray pyrolysis. Journal of Alloys and Compounds, 2012, 541, 495-504.	2.8	67
66	The role of substrate temperature on the properties of nanocrystalline Mo doped ZnO thin films by spray pyrolysis. Ceramics International, 2012, 38, 3875-3883.	2.3	62
67	Realization of stable p-type ZnO thin films using Li <sup>+</sup> /N dual acceptors. Journal of Alloys and Compounds, 2011, 509, 8676-8682.	2.8	36
68	Band gap variation in co-evaporated AgInSe <sub>2</sub> thin films with 1.26 MeV He <sup>+</sup> ion irradiation. Indian Journal of Physics, 2011, 85, 401-409.	0.9	6
69	Effect of annealing on the structural, optical and electrical properties of ZnO thin films by spray pyrolysis. Indian Journal of Physics, 2011, 85, 1381-1391.	0.9	24
70	Effect of iron doping and annealing on structural and optical properties of cerium oxide nanocrystals. Journal of Physics and Chemistry of Solids, 2010, 71, 1020-1025.	1.9	33
71	Physical properties of ZnO thin films deposited at various substrate temperatures using spray pyrolysis. Physica B: Condensed Matter, 2010, 405, 2226-2231.	1.3	155
72	Effect of He <sup>+</sup> irradiation on the optical properties of vacuum evaporated silver indium selenide thin films. Journal of Alloys and Compounds, 2010, 495, 284-287.	2.8	8

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73	Physical properties of Ga-doped ZnO thin films by spray pyrolysis. Journal of Alloys and Compounds, 2010, 506, 788-793.	2.8	128
74	Realization of stable p-type ZnO thin films using a Li-N dual acceptor doping for optoelectronic applications. , 2010, , .		0
75	Effect of thickness on structural, optical and electrical properties of nanostructured ZnO thin films by spray pyrolysis. Applied Surface Science, 2009, 255, 4579-4584.	3.1	201
76	Effect of aluminium doping and annealing on structural and optical properties of cerium oxide nanocrystals. Journal of Physics and Chemistry of Solids, 2009, 70, 1443-1447.	1.9	29
77	Highly oriented (100) ZnO thin films by spray pyrolysis. Applied Surface Science, 2009, 255, 7212-7215.	3.1	67
78	Effect of H <sup>+</sup> irradiation on the optical properties of vacuum evaporated AgInSe <sub>2</sub> thin films. Applied Surface Science, 2009, 255, 8324-8327.	3.1	7
79	Effect of stress on optical band gap of ZnO thin films with substrate temperature by spray pyrolysis. Journal of Alloys and Compounds, 2009, 485, 413-417.	2.8	128
80	ZnO Thin Films for Optoelectronic Applications. , 2009, , .		0
81	Formation and properties of AgInSe <sub>2</sub> thin films by co-evaporation. Vacuum, 2004, 72, 369-378.	1.6	39
82	Photo-electrical properties of silver indium selenide thin films. Journal of Materials Science Letters, 2003, 22, 287-291.	0.5	4
83	Structural, electrical and optical properties of silver selenide thin films. Semiconductor Science and Technology, 2002, 17, 261-265.	1.0	49
84	Transport properties of silver selenide thin films from 100 to 300 K. Materials Letters, 2002, 56, 491-495.	1.3	9
85	Electrical properties of silver selenide thin films prepared by reactive evaporation. Bulletin of Materials Science, 2002, 25, 407-411.	0.8	25
86	Temperature-Dependent Properties of Co-evaporated CuS Thin Films. Brazilian Journal of Physics, 0, , 1.	0.7	4